

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max Tc = +25°C
	$2m\Omega @ V_{GS} = 10V$	205A
60V	$3m\Omega @ V_{GS} = 6V$	170A
	3.3mΩ @ V <sub>GS</sub> = 4.5V	165A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDs(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

PowerDI5060-8 (Type K)

Pin1

Bottom View

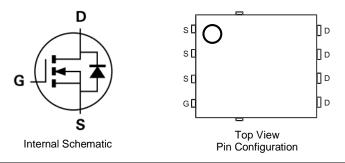
- Switching
- Synchronous Rectification
- DC-DC Converters



- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



# Ordering Information (Note 4)

Top View

Part Number	Case	Packaging
DMTH6002LPS-13	PowerDI5060-8 (Type K)	2,500 / Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

<1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



); !: = Manufacturer's Marking
TH6002LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 21 = 2021)
WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	Tc = +25°C Tc = +100°C	Ы	205 145	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	•	I <sub>DM</sub>	820	А
Continuous Body Diode Forward Current (Note 6)	Tc = +25°C	ls	205	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I <sub>SM</sub>	820	А	
Avalanche Current, L = 3mH	las	14	А	
Avalanche Energy, L = 3mH		EAS	294	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	50	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	167	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	0.9	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

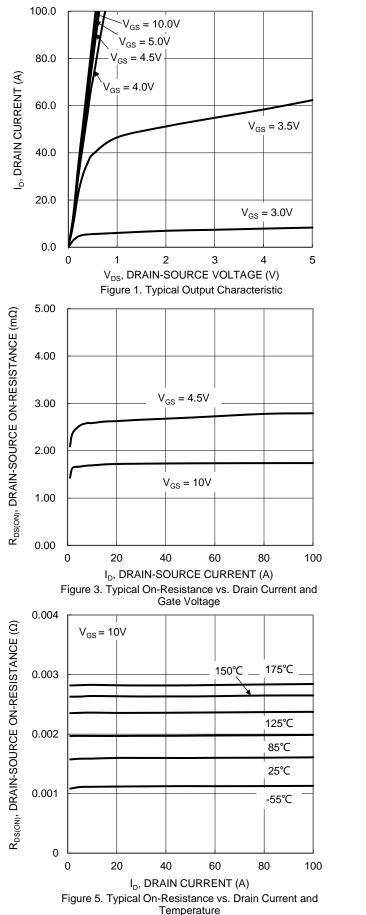
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
		—	1.7	2		V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A	
Static Drain-Source On-Resistance	RDS(ON)	_	2	3	mΩ	Vgs = 6V, ID = 30A	
		_	2.3	3.3		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 30A	
Diode Forward Voltage	Vsd	_	—	1.2	V	VGS = 0V, IS = 50A	
DYNAMIC CHARACTERISTICS (Note 8)			•	•		÷	
Input Capacitance	Ciss	_	6555	_		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	_	2264	_	pF		
Reverse Transfer Capacitance	Crss		187	_			
Gate Resistance	Rg	_	0.7	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	130.8	_		V <sub>DS</sub> = 30V, I <sub>D</sub> = 50A	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	63.6	—	nC		
Gate-Source Charge	Qgs	_	20.8	_	nc		
Gate-Drain Charge	Q <sub>gd</sub>	_	29.4	—			
Turn-On Delay Time	tD(ON)	_	11.2	_		V <sub>DD</sub> = 20V, V <sub>GS</sub> = 10V,	
Turn-On Rise Time	t <sub>R</sub>	_	10.8	—			
Turn-Off Delay Time	tD(OFF)	_	44	_	ns	$I_D = 50A, R_g = 2.5\Omega$	
Turn-Off Fall Time	tF	_	19.5	—	1		
Reverse Recovery Time	trr	_	61.8	_	ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	123	—	nC	$I_F = 50A$ , di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:







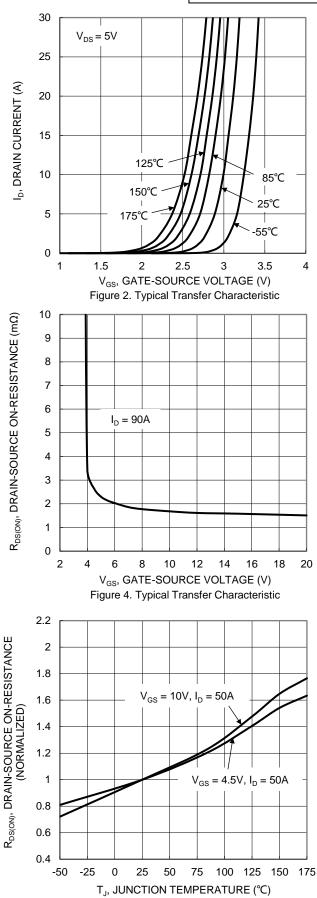
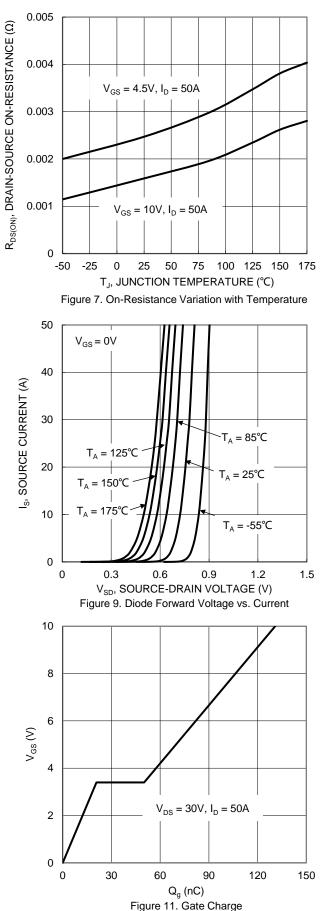


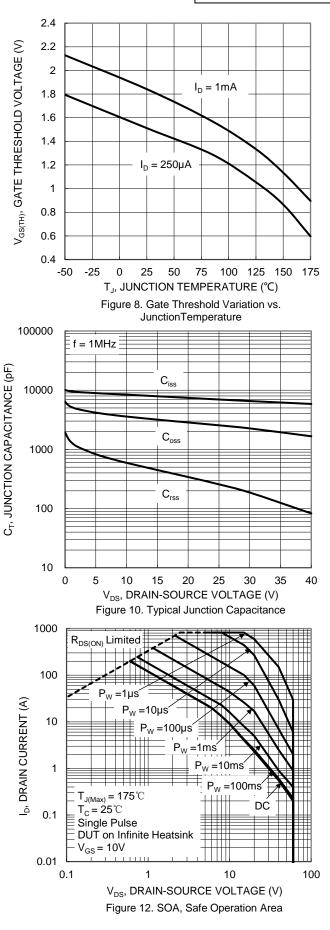
Figure 6. On-Resistance Variation with Temperature

DMTH6002LPS Document number: DS38143 Rev. 8 - 2



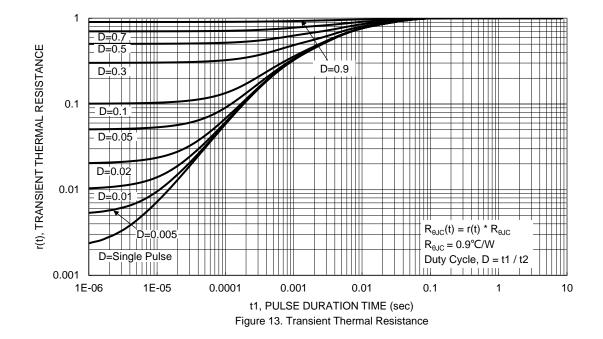






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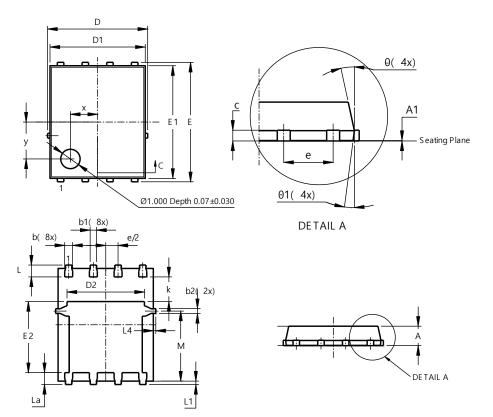






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



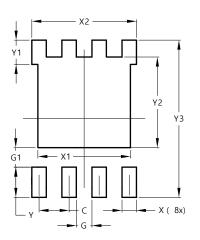
PowerDI5060-8 (Type K)

	PowerDI5060-8 (Type K)					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05	0.02			
b	0.33	0.51	0.41			
b1	0.300	0.366	0.333			
b2	0.20	0.35	0.25			
С	0.23	0.33	0.277			
D	5	.15 BS0	0			
D1	4.85	4.95	4.90			
D2	-	-	3.98			
E E1	6	.15 BS0	0			
E1	5.75	5.85	5.80			
E2	3.56	3.725	3.66			
е	1	.27BSC	, ,			
k	-	-	1.27			
L	0.51	0.71	0.61			
La	0.51	0.675	0.61			
L1	0.05	0.20	0.175			
L4	-	-	0.125			
Μ	3.50	3.71	3.605			
х	-	-	1.400			
У	-	-	1.900			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All	All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (Type K)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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